

5 é / Descriptions

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Schottky Barrier Diode in a TO-220F Plastic Package.

α^a / Features

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Low poer losses, High efficiency operation.

Đ ÷ / Applications

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For use in high frequency inverters, switching power supplies, freewheeling diodes, OR-ing diode, dc-to-dc converters and reverse battery protection.

Ã W] Ô . / Equivalent Circuit

• Û - æ / Pinning

PIN1 y Anode PIN 2 y Cathode PIN 3 y Anode

, M V / Marking

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See Marking Instructions.

MBRF2040CT~MBRF20200CT

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Electrical Characteristics(Ta=25 ;)

Parameter	Symbol	Rating						Unit
		MBRFXCT						
		2040	2045	2060	20100	20150	20200	
Peak Repetitive Reverse Voltage	V _{RM}	40	45	60	100	150	200	V
RMS Reverse Voltage	V _{RMS}	28	32	42	70	105	140	V
DC Blocking Voltage	V _{DC}	40	45	60	100	150	200	V
Average Rectified Forward Current	I _{F(AV)}	10X2						A
Forward Voltage at 10A	V _F	0.70	0.75	0.85	0.90	0.92		V
Instantaneous Reverse Current Ta=25 ; Ta=125 ;	I _R	0.1			0.05			mA
		20			20			
Typical Junction Capacitance ⁽¹⁾	C _J	600	400				pF	
Non Repetitive Peak Surge Current	I _{FSM}	150						A
Thermal Resistance Junction to Case ⁽²⁾	R _{JA}	45						°C/W
Junction and Storage Temperature Range	T _j T _{stg}	-55~150				-55~175		°C

Notes

(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C

(2) P.C.B. mounted with 10cmX10cmX1mm copper pad areas.

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Ø ≡) ϕ / Package Dimensions

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